High Speed GaAlAs Infrared Emitter

OPE5587

The **OPE5587** is GaAlAs infrared emitting diode that is designed for high power, low forward voltage and high speed rise / fall time. This device is optimized for speed and efficiency at emission wavelength 880nm and has a high radiant efficiency over a wide range of forward current. This device is packaged T1-3/4 package and has narrow beam angle with lensed package and cup frame. Especially this device is suited as the emitter of data transmission without cable.

FEATURES

- Ultra high-speed : 25ns rise time
- 880nm wavelength
- Narrow beam angle
- Low forward voltage
- High power and high reliability
- Available for pulse operating

APPLICATIONS

- Emitter of IrDA
- IR Audio and Telephone
- High speed IR communication
- IR LANs
- Available for wireless digital data transmission

STORAGE

- Condition : 5°C~35°C,R.H.60%
- Terms : within 3 months from production date
- Remark : Once the package is opened, the products should be used within a day. Otherwise, it should be keeping in a damp proof box with desiccants.
- * Please take proper steps in order to secure reliability and safety in required conditions and environments for this device.

MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Power dissipation	P _D	150	mW
Forward current	I_F	100	mA
Pulse forward current *1	I _{FP}	1.0	А
Reverse voltage	V _R	4.0	V
Operating temp.	T _{opr.}	-25~+85	°C
Soldering temp. *2	T _{sol.}	260	°C

^{*1}.Duty ratio = 1/100, pulse width=0.1ms.

^{*2}.Lead Soldering Temperature (2mm from case for 5sec.).

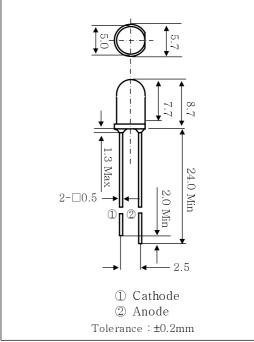
ELECTRO-OPTICALCHARACTERISTICS

Item	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward voltage	$V_{\rm F}$	I _F =50mA		1.5	2.0	V
Reverse current	I _R	V _R =4V			10	μΑ
Capacitance	Ct	f=1MHz		20		pF
Radiant intensity	Ie	I _F =50mA	40	90		mW/sr
Peak emission wavelength	λ_{p}	I _F =50mA		880		nm
Spectral bandwidth 50%	Δλ	I _F =50mA		45		nm
Half angle	$\Delta \theta$	I _F =50mA		±10		deg.
Optical rise & fall time(10%~90%)	tr/tf	I _F =50mA		25/15		ns
Cut off frequency *3	fc	I _F =50mA DC +10mA p-p		14		MHz

DIMENSIONS (Unit:mm)

(Ta=25°C)

 $(Ta=25^{\circ}C)$



*3. 10logPo(fc MHz)/Po(0.1 MHz)=-3

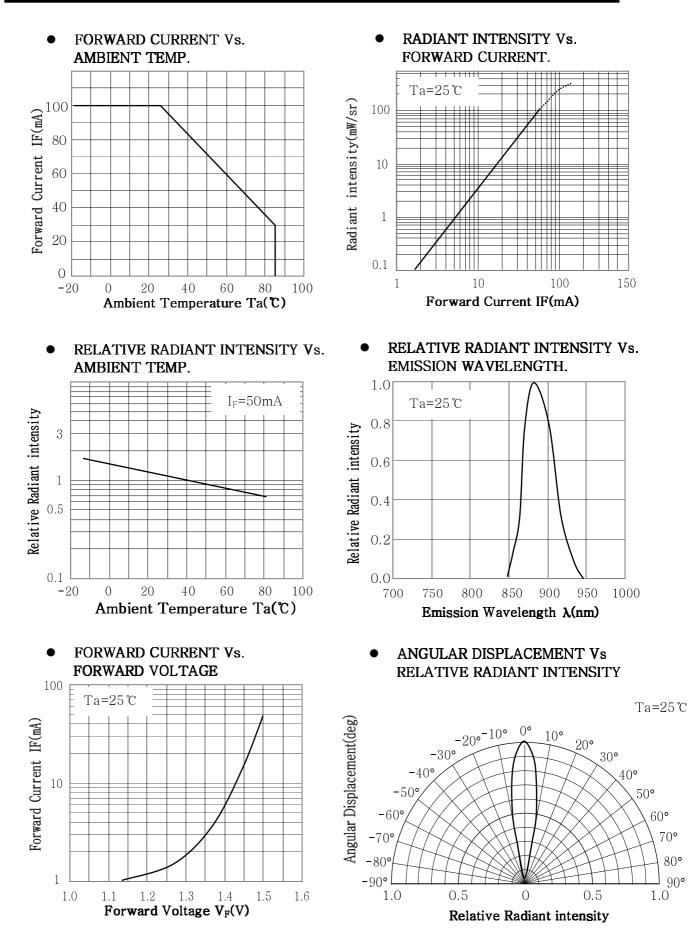
50°

60° 70°

1.0

80°

90°



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